## NSN 5961-01-318-5165

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-318-5165 **Inclosure Material:** Metal **Overall Length:** 27.7 millimeters **Overall Height:** 3.43 millimeters **Overall Width:** 27.7 millimeters **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 250.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 70.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter and 100.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**